

LOGIC-INPUT CMOS QUAD DRIVERS

FEATURES

- High Peak Output Current 1.2A
- Wide Operating Range 4.5 to 18V
- Symmetrical Rise and Fall Times 25nsec
- Short, Equal Delay Times 75nsec
- Latchproof! Withstands 500mA Inductive Kickback
- 3 Input Logic Choices
— AND / NAND / AND + Inv
- 2kV ESD Protection on All Pins

APPLICATIONS

- General-Purpose CMOS Logic Buffer
- Driving All Four MOSFETs in an H-Bridge
- Direct Small Motor Driver
- Relay or Peripheral Drivers
- CCD Driver
- Pin-Switching Network Driver

GENERAL DESCRIPTION

The TC446X family of four-output CMOS buffer/drivers are an expansion from our earlier single- and dual-output drivers. Each driver has been equipped with a two-input logic gate for added flexibility.

The TC446X drivers can source up to 250 mA into loads referenced to ground. Heavily loaded clock lines, coaxial cables, and piezoelectric transducers can all be easily driven with the 446X series drivers. The only limitation on loading is that total power dissipation in the IC must be kept within the power dissipation limits of the package.

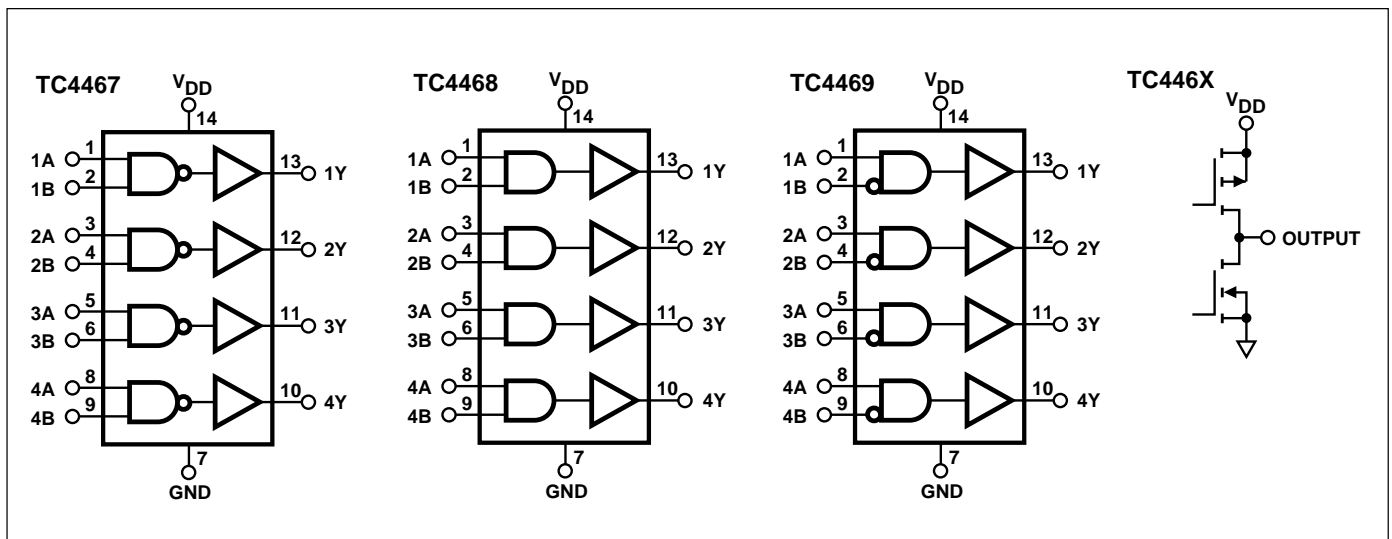
The TC446X series will not latch under any conditions within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking (either polarity) occurs on the ground line. They can accept up to half an amp of inductive kickback current (either polarity) into their outputs without damage or logic upset. In addition, all terminals are protected against ESD to at least 2000V.

ORDERING INFORMATION

Part No.	Package	Temp. Range
TC446xCOE	16-Pin SOIC (Wide)	0° to +70°C
TC446xCPD	14-Pin Plastic DIP	0° to +70°C
TC446xEJD	14-Pin CerDIP	-40° to +85°C
TC446xMJD	14-Pin CerDIP	-55° to +125°C

*A digit must be added in the "x" position to define the device input configuration:
 TC446x — 7 NAND
 8 AND
 9 AND with INV

LOGIC DIAGRAMS



LOGIC-INPUT CMOS QUAD DRIVERS

TC4467
TC4468
TC4469

ABSOLUTE MAXIMUM RATINGS*

Supply Voltage	+20V
Input Voltage	(GND – 5V) to (V _{DD} + 0.3V)
Maximum Chip Temperature	
Operating	+150°C
Storage	– 65° to +150°C
Maximum Lead Temperature	
(Soldering, 10 sec)	+300°C
Operating Ambient Temperature Range	
C Device	0° to +70°C
E Device	– 40° to +85°C
M Device	– 55° to +125°C
Package Power Dissipation (T _A ≤ 70°C)	
14-Pin CerDIP	840mW
14-Pin Plastic DIP	800mW
16-Pin Wide SOIC	760mW

Package Thermal Resistance

14-Pin CerDIP	R _{θJ-A}	100°C/W
	R _{θJ-C}	23°C/W
14-Pin Plastic DIP	R _{θJ-A}	80°C/W
	R _{θJ-C}	35°C/W
16-Pin Wide SOIC	R _{θJ-A}	95°C/W
	R _{θJ-C}	28°C/W

*Static-sensitive device. Unused devices must be stored in conductive material. Protect devices from static discharge and static fields. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to Absolute Maximum Rating Conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS: Measured at T_A = +25°C with 4.5V ≤ V_{DD} ≤ 18V, unless otherwise specified.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
Input						
V _{IH}	Logic 1, High Input Voltage	Note 3	2.4	—	V _{DD}	V
V _{IL}	Logic 0, Low Input Voltage	Note 3	0	—	0.8	V
I _{IN}	Input Current	0V ≤ V _{IN} ≤ V _{DD}	– 1	—	1	μA
Output						
V _{OH}	High Output Voltage	I _{LOAD} = 100μA (Note 1)	V _{DD} – 0.025	—	—	V
V _{OL}	Low Output Voltage	I _{LOAD} = 10mA (Note 1)	—	—	0.15	V
R _O	Output Resistance	I _{OUT} = 10mA, V _{DD} = 18V	—	10	15	Ω
I _{PK}	Peak Output Current		—	1.2	—	A
I _{DC}	Continuous Output Current	Single Output Total Package	—	—	300 500	mA
I	Latch-Up Protection Withstand Reverse Current	4.5V ≤ V _{DD} ≤ 16V	500	—	—	mA
Switching Time						
t _R	Rise Time	Figure 1	—	15	25	nsec
t _F	Fall Time	Figure 1	—	15	25	nsec
t _{D1}	Delay Time	Figure 1	—	40	75	nsec
t _{D2}	Delay Time	Figure 1	—	40	75	nsec
Power Supply						
I _S	Power Supply Current		—	1.5	4	mA
V _{DD}	Power Supply Voltage	Note 2	4.5	—	18	V

TRUTH TABLE

Part No.	TC4467 NAND				TC4468 AND				TC4469 AND/INV			
INPUTS A	H	H	L	L	H	H	L	L	H	H	L	L
INPUTS B	H	L	H	L	H	L	H	L	H	L	H	L
OUTPUTS TC446X	L	H	H	H	H	L	L	L	L	H	L	L

H = High L = Low

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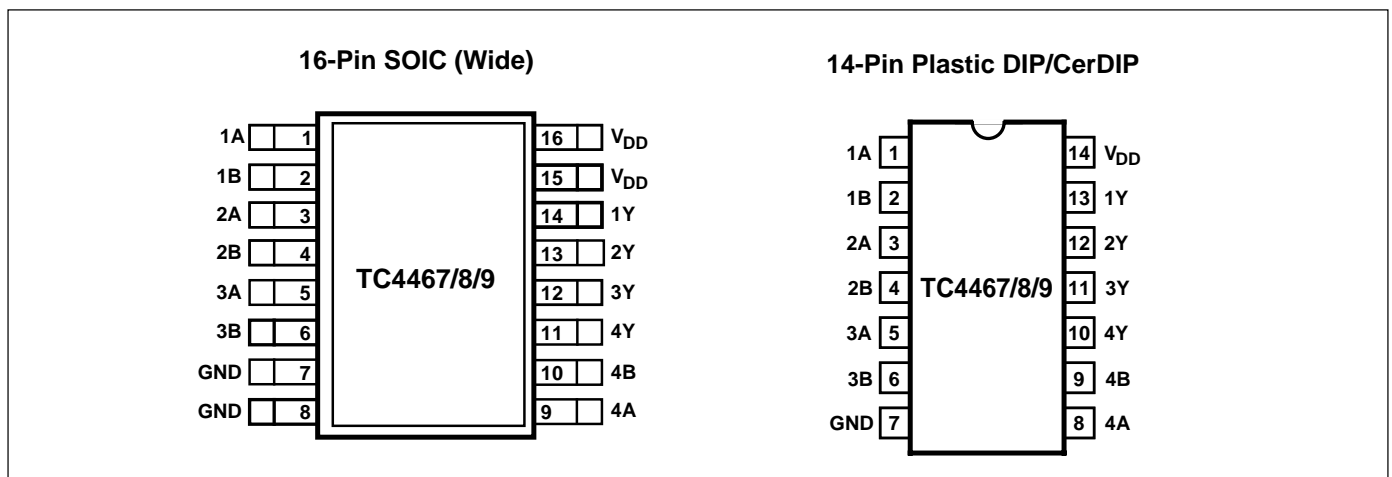
TC4467
TC4468
TC4469

ELECTRICAL CHARACTERISTICS: Measured throughout operating temperature range with $4.5V \leq V_{DD} \leq 18V$, unless otherwise specified.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
Input						
V_{IH}	Logic 1, High Input Voltage	(Note 3)	2.4	—	—	V
V_{IL}	Logic 0, Low Input Voltage	(Note 3)	—	—	0.8	V
I_{IN}	Input Current	$0V \leq V_{IN} \leq V_{DD}$	-10	—	10	μA
Output						
V_{OH}	High Output Voltage	$I_{LOAD} = 100\mu A$ (Note 1)	$V_{DD} - 0.025$	—	—	V
V_{OL}	Low Output Voltage	$I_{LOAD} = 10mA$ (Note 1)	—	—	0.30	V
R_O	Output Resistance	$I_{OUT} = 10mA, V_{DD} = 18V$	—	20	30	Ω
I_{PK}	Peak Output Current		—	1.2	—	A
I	Latch-Up Protection Withstand Reverse Current	$4.5V \leq V_{DD} \leq 16V$	500	—	—	mA
Switching Time						
t_R	Rise Time	Figure 1	—	—	50	nsec
t_F	Fall Time	Figure 1	—	—	50	nsec
t_{D1}	Delay Time	Figure 1	—	—	100	nsec
t_{D2}	Delay Time	Figure 1	—	—	100	nsec
Power Supply						
I_S	Power Supply Current		—	—	8	mA
V_S	Power Supply Voltage	Note 2	4.5	—	18	V

- NOTES:**
1. Totem-pole outputs should not be paralleled because the propagation delay differences from one to the other could cause one driver to drive high a few nanoseconds before another. The resulting current spike, although short, may decrease the life of the device.
 2. When driving all four outputs simultaneously in the same direction, V_{DD} shall be limited to 16V. This reduces the chance that internal dv/dt will cause high-power dissipation in the device.
 3. The input threshold has about 50mV of hysteresis centered at approximately 1.5V. Slow moving inputs will force the device to dissipate high peak currents as the input transitions through this band. Input rise times should be kept below 5 μ sec to avoid high internal peak currents during input transitions. Static input levels should also be maintained above the maximum or below the minimum input levels specified in the "Electrical Characteristics" to avoid increased power dissipation in the device.

PIN CONFIGURATIONS



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Supply Bypassing

Large currents are required to charge and discharge large capacitive loads quickly. For example, charging a 1000pF load to 18V in 25nsec requires 0.72A from the device's power supply.

To guarantee low supply impedance over a wide frequency range, a 1μF film capacitor in parallel with one or two low-inductance 0.1μF ceramic disk capacitors with short lead lengths (<0.5 in.) normally provide adequate bypassing.

Grounding

The TC4467 and TC4469 contain inverting drivers. Potential drops developed in common ground impedances from input to output will appear as negative feedback and degrade switching speed characteristics. Instead, individual ground returns for input and output circuits, or a ground plane, should be used.

Input Stage

The input voltage level changes the no-load or quiescent supply current. The N-channel MOSFET input stage transistor drives a 2.5mA current source load. With logic "0" outputs, maximum quiescent supply current is 4mA. Logic "1" output level signals reduce quiescent current to 1.4mA maximum. Unused driver inputs must be connected to V_{DD} or V_{SS} . Minimum power dissipation occurs for logic "1" outputs.

The drivers are designed with 50mV of hysteresis. This provides clean transitions and minimizes output stage current spiking when changing states. Input voltage thresholds are approximately 1.5V, making any voltage greater than 1.5V up to V_{DD} a logic 1 input. Input current is less than 1 μA over this range.

Power Dissipation

The supply current versus frequency and supply current versus capacitive load characteristic curves will aid in determining power dissipation calculations. TelCom Semiconductor's CMOS drivers have greatly reduced quiescent DC power consumption.

Input signal duty cycle, power supply voltage and load type, influence package power dissipation. Given power dissipation and package thermal resistance, the maximum ambient operating temperature is easily calculated. The 14-pin plastic package junction-to-ambient thermal resistance is 83.3°C/W. At +70°C, the package is rated at 800mW maximum dissipation. Maximum allowable chip temperature is +150°C.

Three components make up total package power dissipation:

- (1) Load-caused dissipation (P_L)
- (2) Quiescent power (P_Q)
- (3) Transition power (P_T).

A capacitive-load-caused dissipation (driving MOSFET gates), is a direct function of frequency, capacitive load, and supply voltage. The power dissipation is:

$$P_L = f C V_S^2,$$

where: f = Switching frequency
 C = Capacitive load
 V_S = Supply voltage.

A resistive-load-caused dissipation for ground-referenced loads is a function of duty cycle, load current, and load voltage. The power dissipation is:

$$P_L = D (V_S - V_L) I_L,$$

where: D = Duty cycle
 V_S = Supply voltage
 V_L = Load voltage
 I_L = Load current.

A resistive-load-caused dissipation for supply-referenced loads is a function of duty cycle, load current, and output voltage. The power dissipation is:

$$P_L = D V_O I_L,$$

where: f = Switching frequency
 V_O = Device output voltage
 I_L = Load current.

Quiescent power dissipation depends on input signal duty cycle. Logic HIGH outputs result in a lower power dissipation mode, with only 0.6 mA total current drain (all devices driven). Logic LOW outputs raise the current to 4 mA maximum. The quiescent power dissipation is:

$$P_Q = V_S (D(I_H) + (1-D)I_L),$$

where: I_H = Quiescent current with all outputs LOW (4 mA max)
 I_L = Quiescent current with all outputs HIGH (0.6mA max)
 D = Duty cycle
 V_S = Supply voltage.

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Transition power dissipation arises in the complementary configuration (TC446X) because the output stage N-channel and P-channel MOS transistors are ON simultaneously for a very short period when the output changes. The transition power dissipation is approximately:

$$P_T = f V_S (10 \times 10^{-9}).$$

Package power dissipation is the sum of load, quiescent and transition power dissipations. An example shows the relative magnitude for each term:

C = 1000pF capacitive load

V_S = 15V

D = 50%

f = 200kHz

P_D = Package Power Dissipation = P_L + P_Q + P_T
 = 45mW + 35 mW + 30 mW = 110mW.

Maximum operating temperature:

$$T_J - \theta_{JA} (P_D) = 141^\circ\text{C},$$

where: T_J = Maximum allowable junction temperature (+150°C)

θ_{JA} = Junction-to-ambient thermal resistance (83.3°C/W) 14-pin plastic package.

NOTE: Ambient operating temperature should not exceed +85°C for "EJD" device or +125°C for "MJD" device.

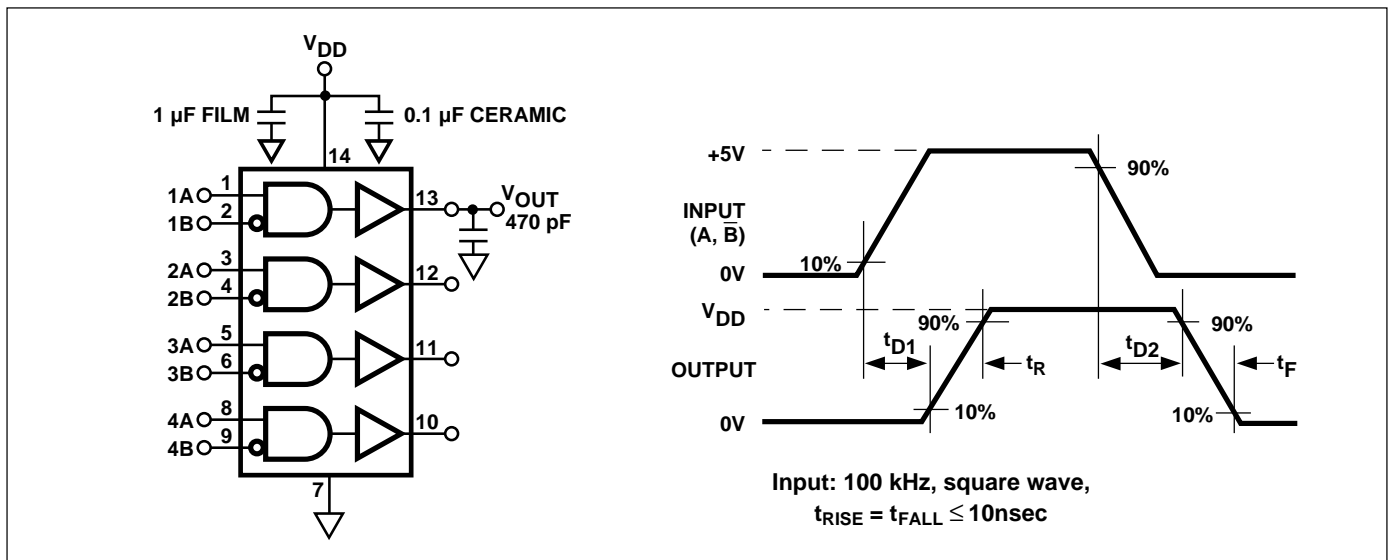


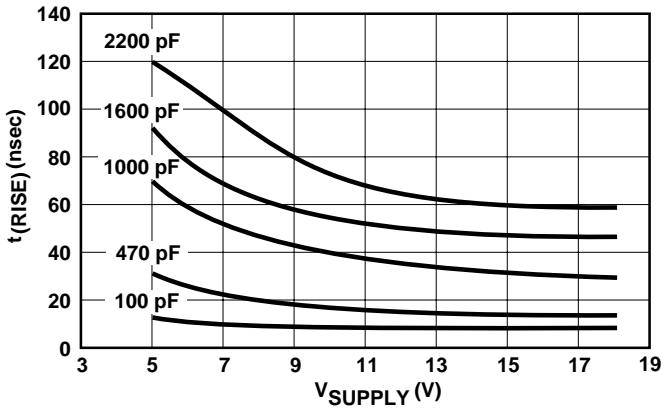
Figure 1. Switching Time Test Circuit

LOGIC-INPUT CMOS QUAD DRIVERS

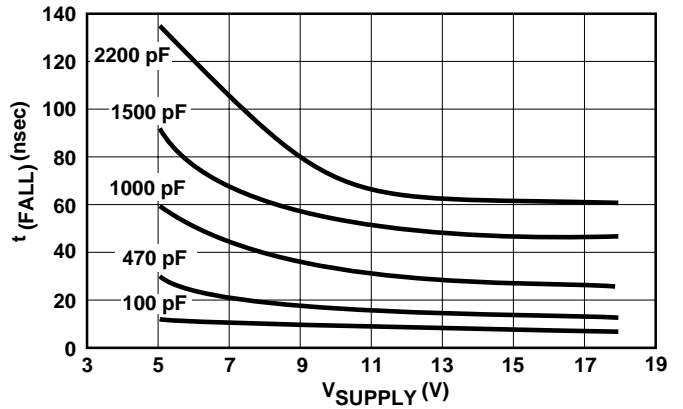
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TYPICAL CHARACTERISTICS

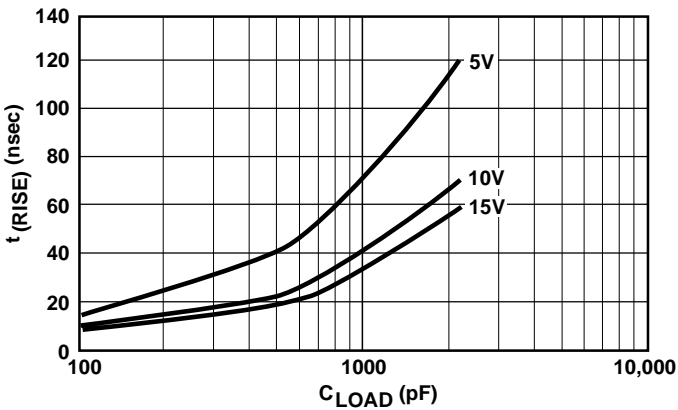
Rise Time vs. Supply Voltage



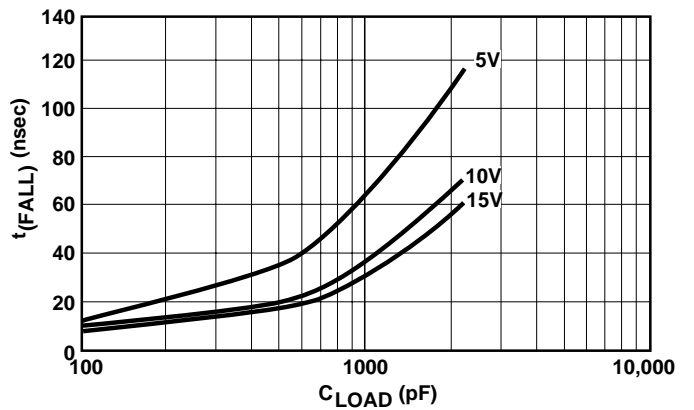
Fall Time vs. Supply Voltage



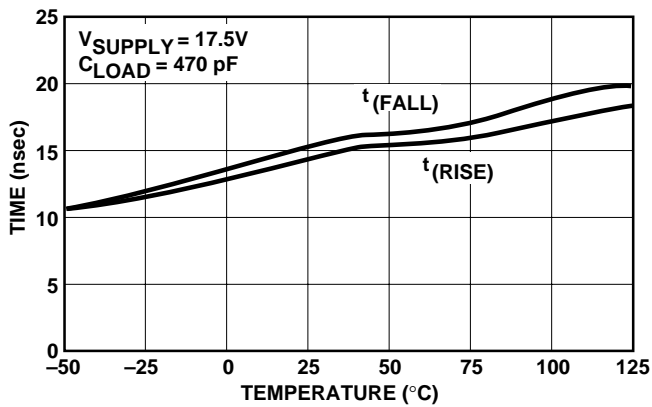
Rise Time vs. Capacitive Load



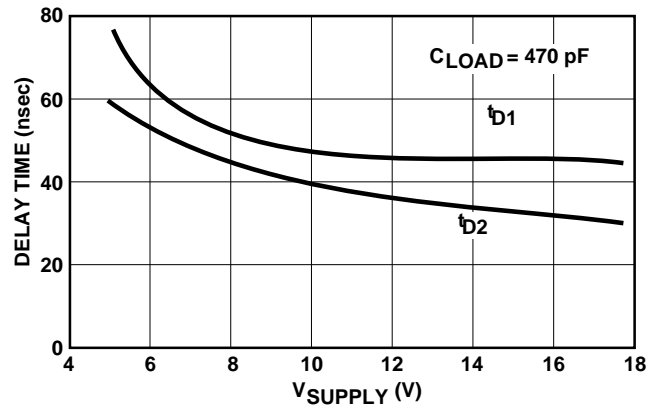
Fall Time vs. Capacitive Load



Rise/Fall Times vs. Temperature



Propagation Delay Time vs. Supply Voltage

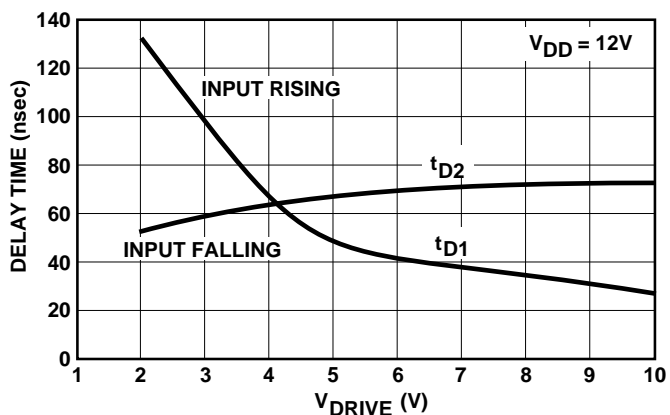


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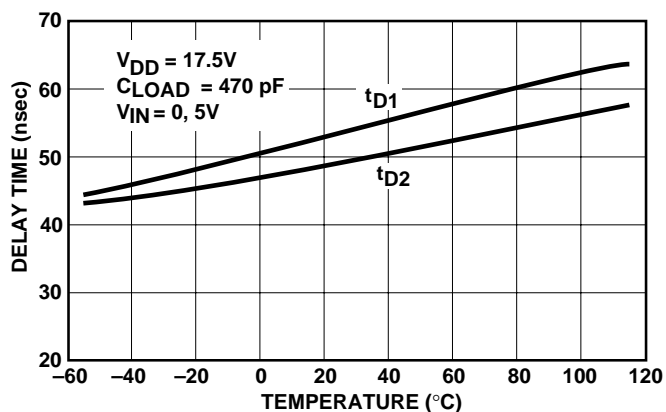
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TYPICAL CHARACTERISTICS (Cont.)

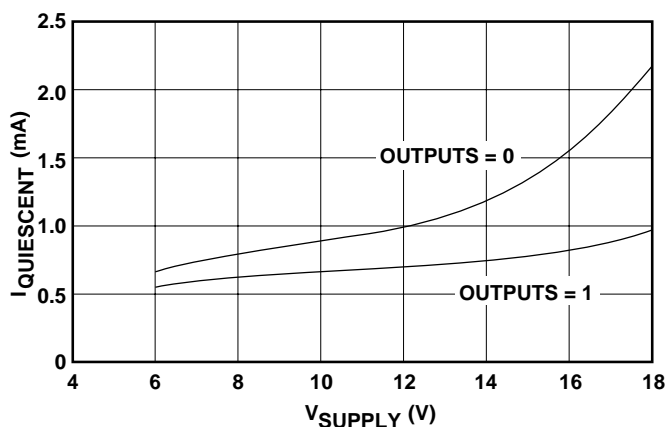
Input Amplitude vs. Delay Times



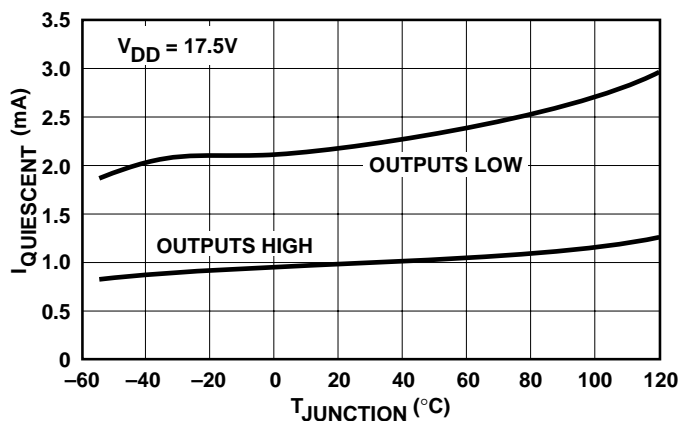
Propagation Delay Times vs. Temperature



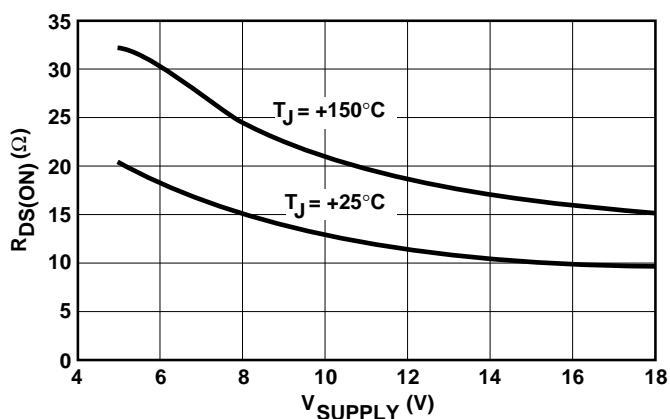
Quiescent Supply Current vs. Supply Voltage



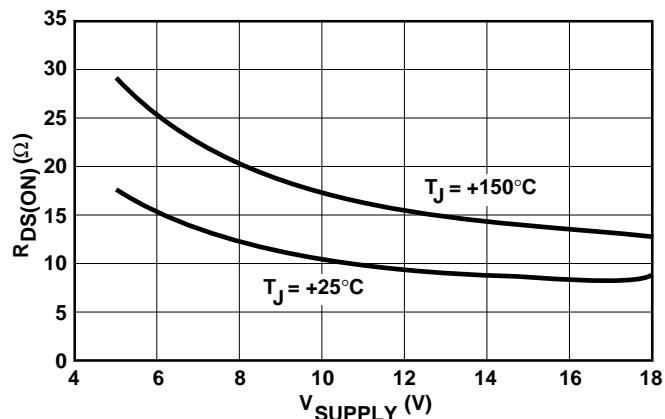
Quiescent Supply Current vs. Temperature



High-State Output Resistance



Low-State Output Resistance

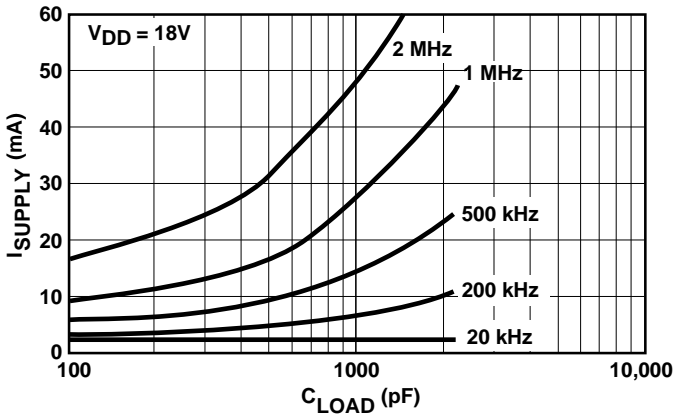


LOGIC-INPUT CMOS QUAD DRIVERS

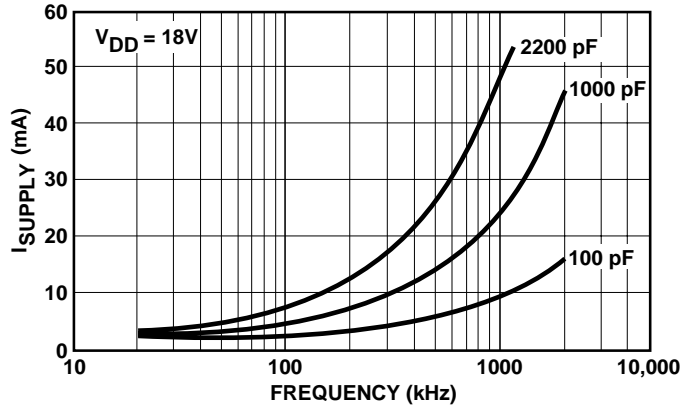
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SUPPLY CURRENT CHARACTERISTICS (Load on Single Output Only)

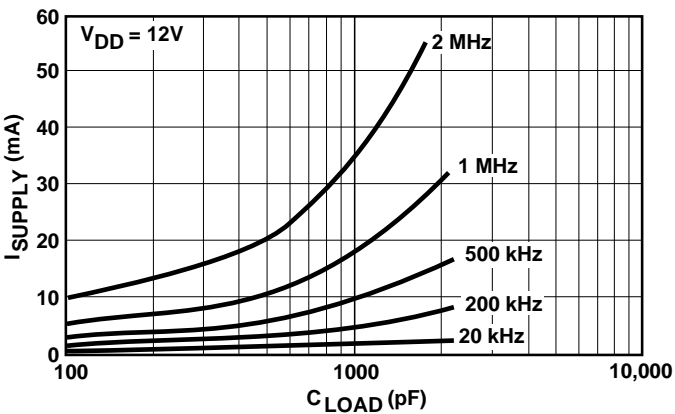
Supply Current vs. Capacitive Load



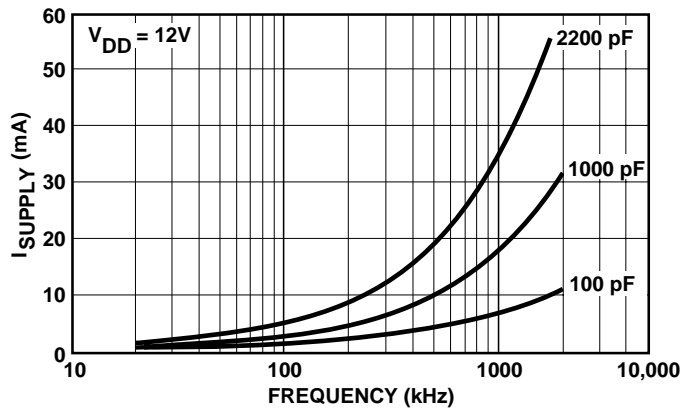
Supply Current vs. Frequency



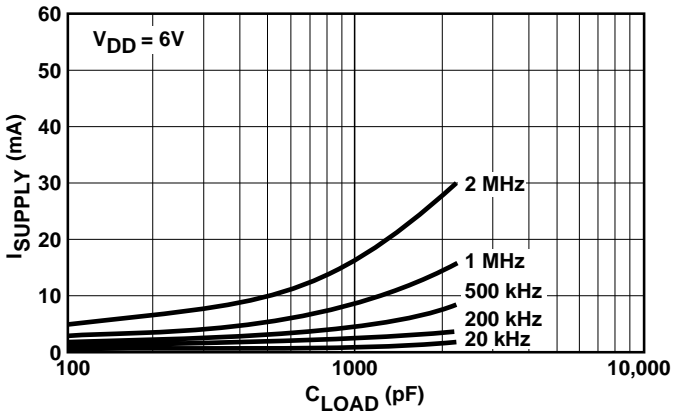
Supply Current vs. Capacitive Load



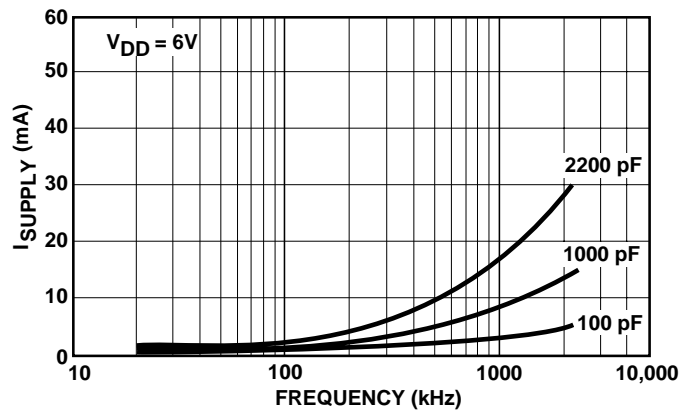
Supply Current vs. Frequency



Supply Current vs. Capacitive Load



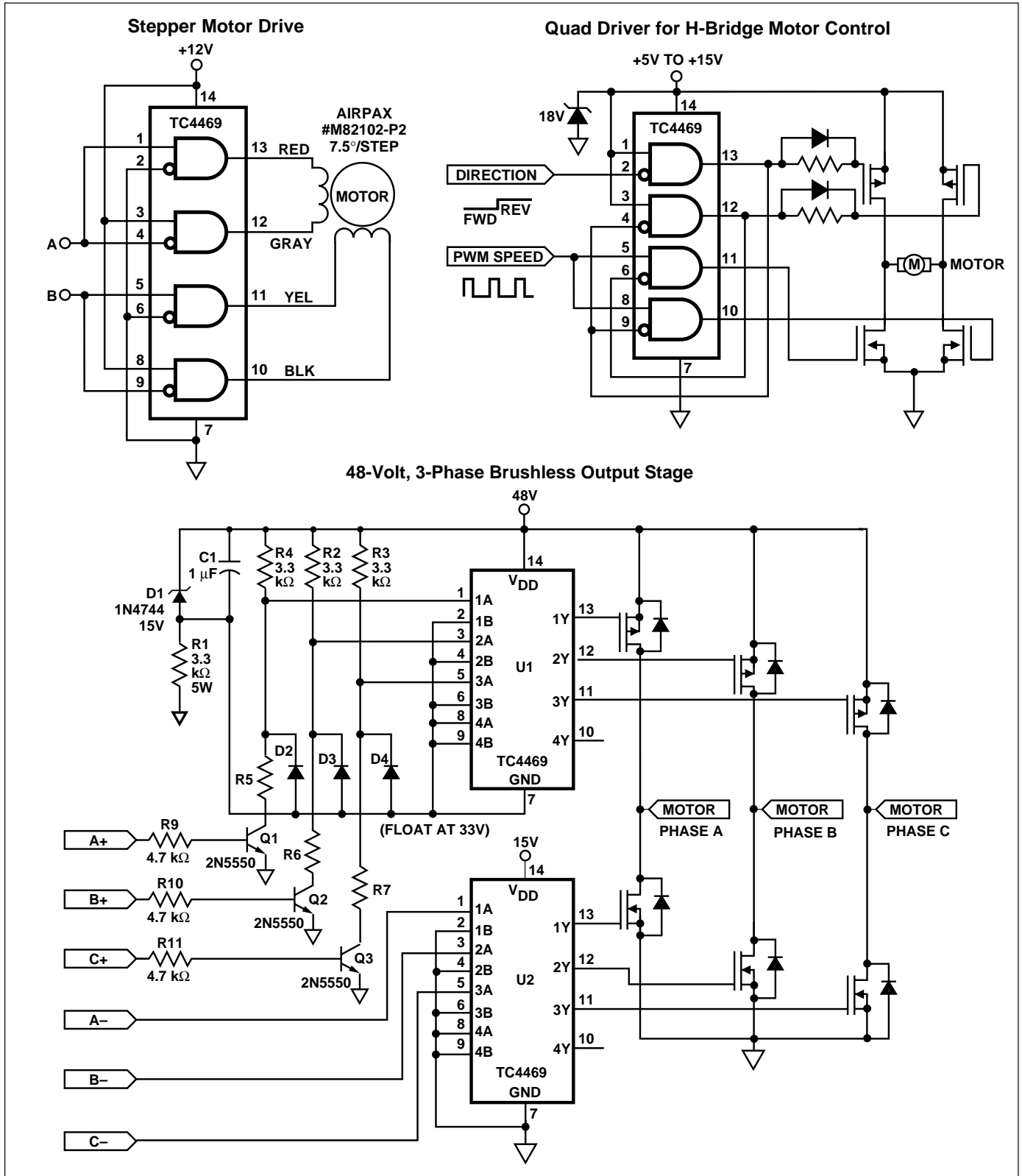
Supply Current vs. Frequency



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TYPICAL APPLICATIONS

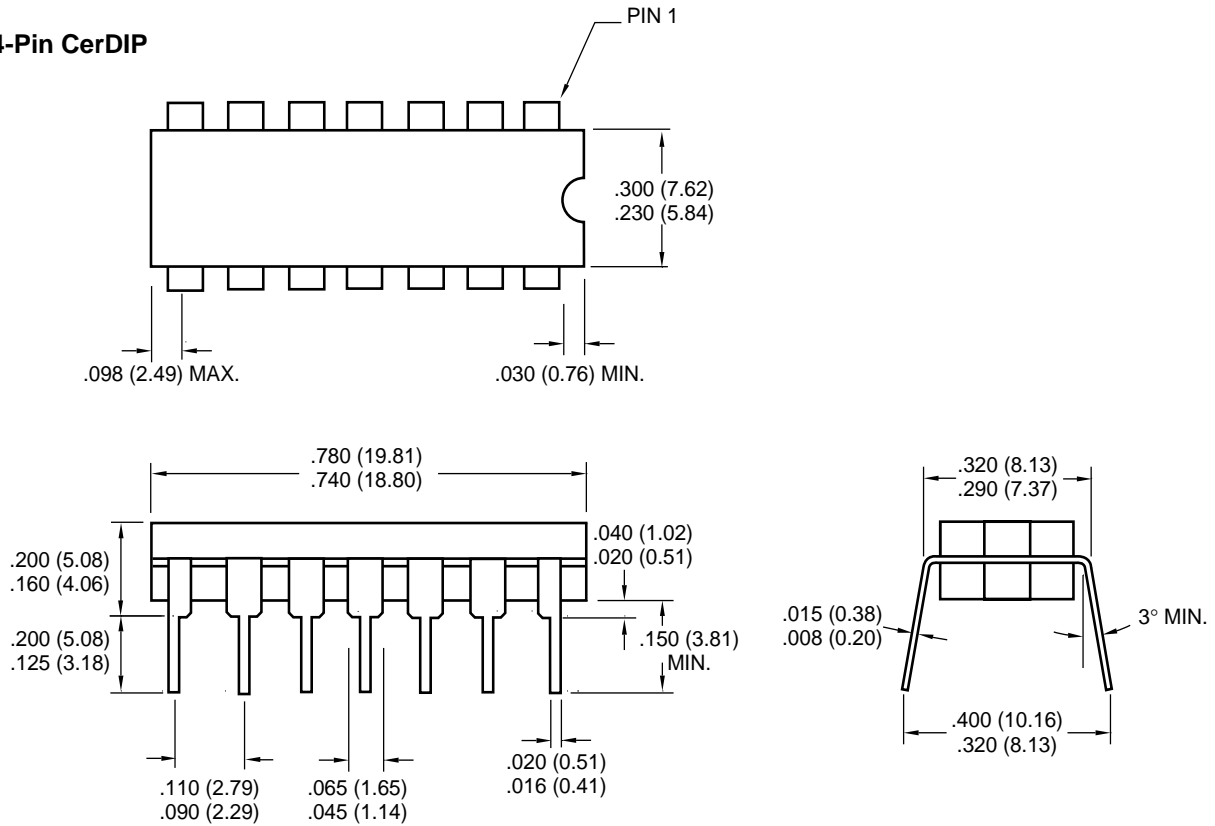


LOGIC-INPUT CMOS QUAD DRIVERS

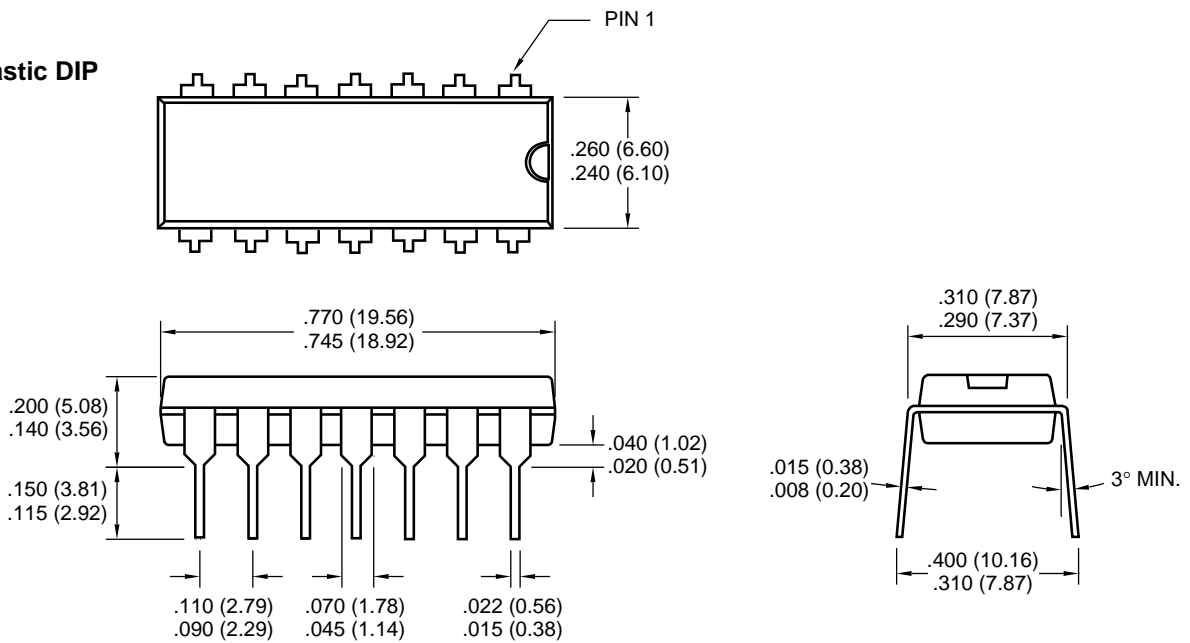
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PACKAGE DIMENSIONS

14-Pin CerDIP



14-Pin Plastic DIP

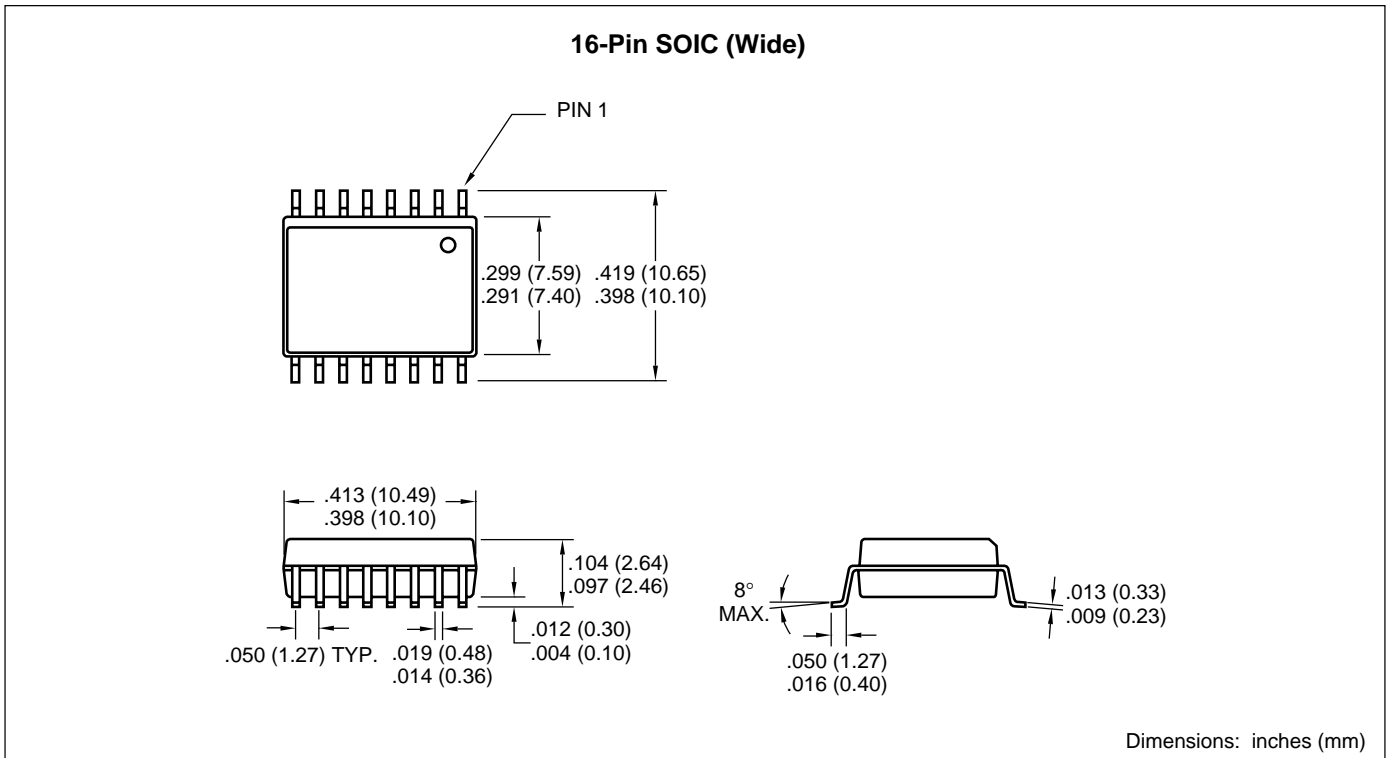


Dimensions: inches (mm)

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PACKAGE DIMENSIONS (Cont.)





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